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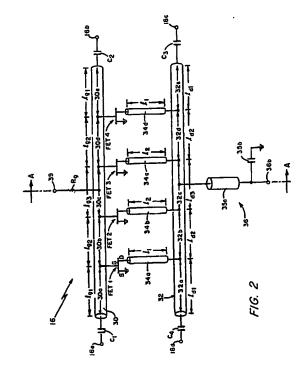
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(5) Symmetric bi-directional amplifier.

(57) A transceiver module (10) includes a bi-directional amplifier (16) having a pair of symmetric signal paths for amplification of both transmit and receive signals. The bi-directional amplifier (16) is disposed between a pair of r.f. switches (14, 18) to provide a pair of signal paths between two terminals of the module (10). The amplifier (16) has an input propagation network (30) coupling two input terminals (16a, 16b), and an output propagation network (32) coupling two output terminals (16c, 16d). A plurality of FETs (FET1, FET2, FET3, FET4) have their gates connected to the input propagation network (30) and their drains connected to the output propagation network (32). Electrical paths lengths are selected so that an input signal at one input terminal (16a) propagates with amplification to one output terminals (16c) and an input signal at the other input terminal (16b) propagates with amplification to the other output terminal (16d).



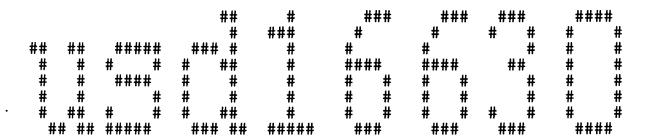
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EUROPEAN SEARCH REPORT

EP 90 31 2494

D	OCUMENTS CONS	DERED TO BE RE	LEVANT		
ategory		th Indication, where appropriate, evant passages		levant claim	CLASSIFICATION OF THE APPLICATION (Int. Cl.5)
Y	CORP.)	AL RESEARCH DEVELOPNine 4; page 4, lines 11-18; p			H 03 F 3/62 H 03 F 3/60
Y	EP-A-0 216 432 (PHILIPS * Column 4, line 17 - colum	•	1-5		
Y	US-A-4 752 746 (K.B. NIC * Figure 2; column 2, lines	:LAS) 15-30; column 4, lines 35-40	1-5		
Α			9		
A	pages 264-265, Stevenage,		t al.:		
P,A	IEEE MTT-S INTERNATIONAL MICROWAVE SYMPOSIUM DIGEST, Dallas, Texas, 8th - 10th May 1990, vol. 2, pages 907-910; T. TSUKII et al.: "Wideband bidirectional MMIC amplifiers for new generation T/R module"				TECHNICAL FIELDS SEARCHED (Int. Cl.5)
	* Figures 1A,1B,2A; page 9 line 4; page 908, column 1,		nn 2,		H 03 F
	Place of search	Date of completion of sea	rch	<u></u> İ	Examiner
	The Hague	20 August 91			WALDORFF U.
Y: A:	CATEGORY OF CITED DOC particularly relevant if taken alone particularly relevant if combined wi document of the same catagory technological background non-written disclosure	th another	the filing da coment of document of	ate cited in the cited for o	ther reasons
Y: A: O: P:	particularly relevant if taken alone particularly relevant if combined wi document of the same catagory	th another	the filing da coment of document of	ate cited in the cited for o	application ther reasons



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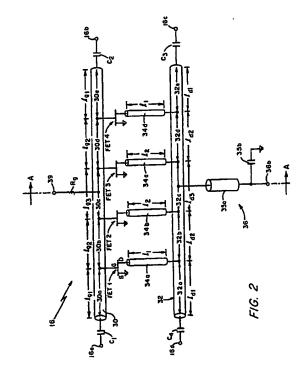
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A	pages 264-265, Stevenage,		al.:	ŀ	
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	The present search report has t				
	Place of search	Date of completion of searc	:n		Examiner
	The Hague	20 August 91			WALDORFF U.
Y: A: O: P:	CATEGORY OF CITED DOCL particularly relevant if taken alone particularly relevant if combined wit document of the same category technological background non-written disclosure intermediate document theory or principle underlying the in	h another D: L: &:	the filing d document document	ate cited in th cited for e	nent, but published on, or after ne application other reasons ne patent family, corresponding